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APPLICATION NO.	F	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/808,469		03/25/2004	Tomohisa Hamano	Q80134	6291
23373	7590	05/11/2005		EXAMINER	
SUGHRUI		PLLC IA AVENUE, N.W.	AMARI, ALESSANDRŌ V		
SUITE 800	SILVAN	IA A V LNO L, N. W.		ART UNIT	PAPER NUMBER
WASHING	WASHINGTON, DC 20037			2872	

DATE MAILED: 05/11/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

	1		H.H
	Application No.	Applicant(s)	
	10/808,469	HAMANO ET AL.	
Office Action Summary	Examiner	Art Unit	
	Alessandro V. Amari	2872	
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet with the c	correspondence address	
A SHORTENED STATUTORY PERIOD FOR REPL' THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period volume to reply within the set or extended period for reply will, by statute - Any reply received by the Office later than three months after the mailing - earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be tin y within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from , cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).	
Status			
1) Responsive to communication(s) filed on 25 F	ebruary 2005.	•	
·_ · _ ·	action is non-final.		
3) Since this application is in condition for allowa	nce except for formal matters, pro	secution as to the merits is	
closed in accordance with the practice under E	Ex parte Quayle, 1935 C.D. 11, 4	53 O.G. 213.	
Disposition of Claims			
 4) ☐ Claim(s) 24-28,40-45,52 and 53 is/are pending 4a) Of the above claim(s) is/are withdray 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 24,25,27,41,52 and 53 is/are rejected. 7) ☐ Claim(s) 26,28,40 and 42-45 is/are objected to 8) ☐ Claim(s) are subject to restriction and/or 	wn from consideration. d. o.		
Application Papers			
9) The specification is objected to by the Examine	er.		
10)☐ The drawing(s) filed on is/are: a)☐ acc	epted or b) objected to by the	Examiner.	
Applicant may not request that any objection to the	drawing(s) be held in abeyance. Se	e 37 CFR 1.85(a).	
Replacement drawing sheet(s) including the correct	, , , , , , , , , , , , , , , , , , , ,		
11) The oath or declaration is objected to by the Ex	caminer. Note the attached Office	Action or form PTO-152.	
Priority under 35 U.S.C. § 119	. ()		
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document 2. Certified copies of the priority document 3. Copies of the certified copies of the priority document application from the International Burear * See the attached detailed Office action for a list	is have been received. Is have been received in Application Introduce the second in Application in the second in t	ion No ed in this National Stage	
See the attached detailed Office action for a list	or the certified copies flot receive		
Attachment(s)		·	
1) X Notice of References Cited (PTO-892)	4) Interview Summary		
2) D Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail D		
 Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date 	6) Other:	aton Application (F 10-132)	

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DETAILED ACTION

Claim Objections

1. Claims 28, 44 and 45 are objected to because of the following informalities:

Regarding claim 28, line 2, the phrase, "the number of steps" has no prior mention in claim 24 on which claim 28 is dependent.

Regarding claim 44, the phrase, "the number of steps" has no prior mention in claims 24 and 26 on which claim 44 is dependent.

Regarding claim 45, line 2, the phrase, "the number of steps" has no prior mention in claims 24 or 27 on which claim 45 is dependent.

It appears that the above claims should have been dependent from the other independent claim 25 and so have not been treated further on the merits.

Appropriate correction is required.

Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 24, 25, 52 and 53 are rejected under 35 U.S.C. 103(a) as being unpatentable over Sekine US 6,417,940 in view of Taniguchi et al US 5,543,228.

In regard to claims 24 and 25, Sekine discloses (see Figure 1) a process for fabricating a computer-generated hologram (2) by defining a range which diffraction light obtained by diffraction of incident light leaves as described in column 2, lines 55-

67, determining a hologram phase distribution for allowing said diffraction light to leave the defined range as described in column 3, lines 11-30, quantizing a determined phase distribution to find a quantized depth of a hologram relief and the number of steps of said depth and photoetching a substrate on the basis of found quantized depth or repeating photoetching given times corresponding to an obtained depth and the number of steps as described in column 3, lines 37-67 and column 4, lines 42-65.

However, regarding claims 24 and 25, Sekine does not teach forming a relief on a substrate by photoetching on the basis of a found quantized depth or repeating photoetching given times corresponding to an obtained depth and the number of steps to obtain a relief pattern and patterning a resin layer using said relief pattern to form a hologram relief on a surface of said resin layer. Further, regarding claims 52 and 53, Sekine does not teach wherein the step of patterning a resin layer using said relief pattern to form a hologram relief on the surface of said resin layer includes pressing the relief pattern against the resin layer and then curing the resin layer.

In regard to claims 24 and 25, Taniguchi et al teaches (see Figures 2(a)-2(f), 11(a)-11(c)) forming a relief on a substrate (1, 81) by photoetching on the basis of a found quantized depth to obtain a relief pattern (87), and patterning a resin layer (2, 89) using said relief pattern to form a hologram relief on a surface of said resin layer as described in column 3, lines 3-14 and column 8, lines 12-55.

Regarding claims 52 and 53, Taniguchi et al teaches (see Figures 11(a)-11(d)) the step of patterning a resin layer using said relief pattern to form a hologram relief on the surface of said resin layer includes pressing the relief pattern against the resin layer

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and then curing the resin layer as shown in Figure 11(c) and as described in column 8, lines 12-55.

It would have been obvious to one having ordinary skill in the art at the time the invention was made to utilize the process of forming a relief on a substrate and patterning, pressing and curing a resin layer as taught by Taniguchi et al with the process of determining a hologram phase distribution and quantizing a determined distribution as taught by Sekine in order that neither peeling nor change of optical properties will occur in order to form a more stable hologram and to lengthen the life of the hologram.

4. Claims 27 and 41 are rejected under 35 U.S.C. 103(a) as being unpatentable over Sekine US 6,417,940 in view of Taniguchi et al US 5,543,228 and further in view of Veldkamp et al US 4,846,552.

Regarding claims 27 and 41, Sekine in view of Taniguchi et al teaches the invention as set forth above but regarding claims 27 and 41, does not teach an optical reflective layer laminated on and along a relief side or other side of said resin layer.

Regarding claims 27 and 41, Veldkamp et al teaches (see Figure 1) an optical reflective layer (102) laminated on and along a relief side or other side of said resin layer.

It would have been obvious to one having ordinary skill in the art at the time the invention was made to utilize the optical reflective layer as taught by Veldkamp et al in the hologram of Sekine in view of Taniguchi et al in order to achieve a higher quality and a higher diffractive efficiency hologram.

Allowable Subject Matter

5. Claim 26, 40, 42 and 43 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

6. Claims 26 and 40 are allowable over the prior art for at least the reason that the prior art fails to teach or reasonably suggest, "relief is formed on the basis of a phase distribution obtained by repeatedly arranging a phase distribution of said elemental hologram piece across said substrate" as set forth in the claimed combination. Claim 42 is also allowable based upon its dependence on claim 24.

Claim 43 is allowable over the prior art for at least the reason that the prior art fails to teach or reasonably suggest, "the number of steps L having a depth of said relief is the N-th power of 2 where N is the number of photoetching cycles" as set forth in the claimed combination.

The prior art of record teaches a process for fabricating a computer-generated hologram by defining a range, determining the hologram phase distribution, quantizing a determined phase distribution to find a quantized depth of a hologram forming a relief on a substrate by photoetching or repeating photoetching given times corresponding to an obtained depth and the number of steps to form a relief pattern, patterning a resin layer using the relief pattern to form a hologram relief on a surface of the resin layer. However, the prior art of record does not teach that the relief is formed on the basis of a phase distribution obtained by repeatedly arranging a phase distribution of said elemental hologram piece across said substrate or that the number of steps L having a

depth of said relief is the N-th power of 2 where N is the number of photoetching cycles and there is no motivation or teaching to modify this difference as derived.

Response to Arguments

7. Applicant's arguments with respect to claims 24, 26-28, 42, 44, 45 and 52 have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

- 8. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Slinger US 6,043,910 teaches a process for fabricating a computer-generated hologram.
- 9. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Alessandro V. Amari whose telephone number is (571) 272-2306. The examiner can normally be reached on Monday-Friday 8:00 AM to 5:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Drew Dunn can be reached on (571) 272-2312. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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ava*(1/4* 03 May 2005

Messendro amari

Alessandro Amari

Examiner AU 2872